NSN 5962-01-515-0577

Memory Microcircuit - Page 1 of 1



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End Application:

Test station r-iais 4920-01-495-9100, e/i f-16

Features Provided:

Electrostatic sensitive

Inclosure Configuration:

Dual-in-line

Memory Device Type:

Ram

Memory Capacity:

256mb

Special Features:

Consists of 2ea 128mb 266mhz double data rate sdram, necc, modules

Terminal Type And Quantity:

184 leadless

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0